SQD50034E

www.vishay.com

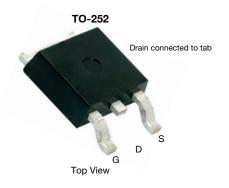
Vishay Siliconix

RoHS

COMPLIANT HALOGEN

FREE

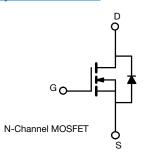
Automotive N-Channel 60 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0039			
I _D (A)	100			
Configuration	Single			
Package	TO-252			

FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_g and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATING	S (T _C = 25 °C, unless	otherwise noted)	
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	60	V
Gate-source voltage	V _{GS}	± 20		
Continuous drain current	$T_C = 25 \ ^{\circ}C \ ^{a}$	1	100	
	T _C = 125 °C	Ι _D	66	
Continuous source current (diode conduction	I _S	97	А	
Pulsed drain current ^b		I _{DM}	320	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	50	
Single pulse avalanche energy	L = 0.1 mm	E _{AS}	125	mJ
Maximum power dissipation ^b	T _C = 25 °C	P _D	107	W
	T _C = 125 °C		35	vv
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^c	R _{thJA}	50	°C/W	
Junction-to-case (drain)		R _{thJC}	1.4	0/10	

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)

www.vishay.com

SQD50034E

Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		•		•		•		
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$		60	-	-	v	
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$		2.5	3.0	3.5	v	
Gate-source leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	-	± 100	nA	
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V V _{DS} = 60 V		-	-	1		
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 175 °C	-	-	300	μA	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	100	-	-	Α	
		V _{GS} = 10 V	I _D = 20 A	-	0.0032	0.0039	1	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A, T _J = 125 °C	-	-	0.0064	Ω	
		$V_{GS} = 10 V$	I _D = 20 A, T _J = 175 °C	-	-	0.0079		
Forward transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		-	135	-	S	
Dynamic ^b		•		•		•	•	
Input capacitance	Ciss			-	4841	6600	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	2243	3100		
Reverse transfer capacitance	C _{rss}			-	60	85		
Total gate charge ^c	Qg	V _{GS} = 10 V V _{DS} = 30 V, I _D = 50 A		-	58	90	nC	
Gate-source charge ^c	Q _{gs}			-	24	-		
Gate-drain charge ^c	Q _{gd}				5	-		
Gate resistance	Rg	f = 1 MHz		0.6	1.26	1.9	Ω	
Turn-on delay time ^c	t _{d(on)}	$V_{DD} = 30 \text{ V}, \text{ R}_{\text{L}} = 0.6 \Omega$ $\text{I}_{\text{D}} \cong 50 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		-	19	30		
Rise time ^c	t _r			-	10	20		
Turn-off delay time ^c	t _{d(off)}			-	30	50	ns	
Fall time ^c	t _f			-	8	15		
Source-Drain Diode Ratings and Chara	cteristics ^b							
Pulsed current ^a	I _{SM}			-	-	320	Α	
Forward voltage	V _{SD}	$I_F = 25 \text{ A}, V_{GS} = 0 \text{ V}$		-	0.83	1.5	V	
Body diode reverse recovery time	t _{rr}	I _F = 30 A, di/dt = 100 A/μs		-	50	100	ns	
Body diode reverse recovery charge	Q _{rr}			-	55	110	nC	
Reverse recovery fall time	ta			-	24	-		
Reverse recovery rise time	t _b			-	26	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.92	-	Α	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

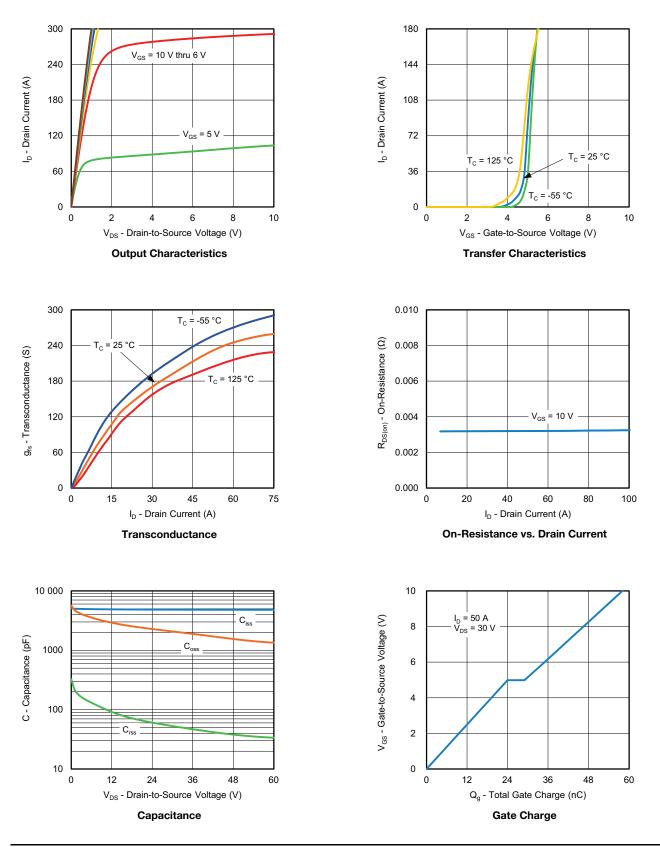
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



S18-1179-Rev. A, 03-Dec-2018

3

Document Number: 79706

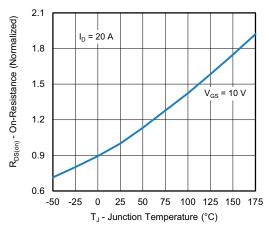
For technical questions, contact: <u>automostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From <u>Oneyac.com</u> <u>w.vishay.com/doc?91000</u>



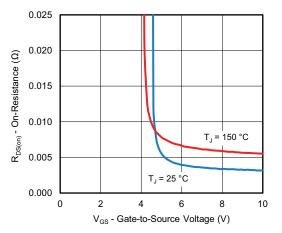
SQD50034E

Vishay Siliconix

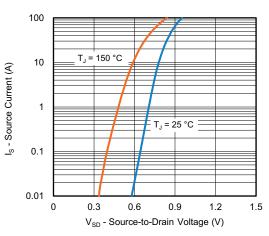
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



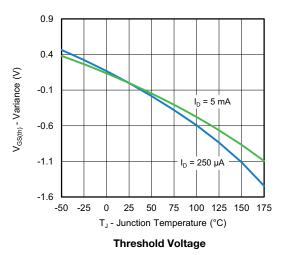
On-Resistance vs. Junction Temperature

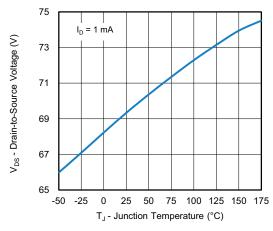


On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



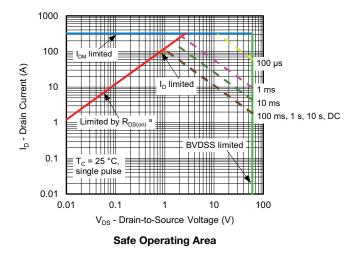


Drain Source Breakdown vs. Junction Temperature

4

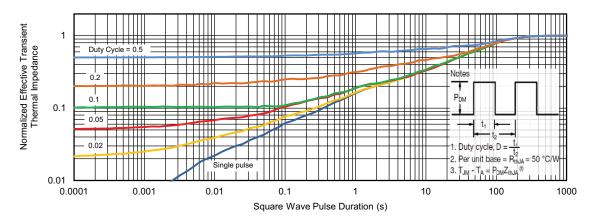


THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



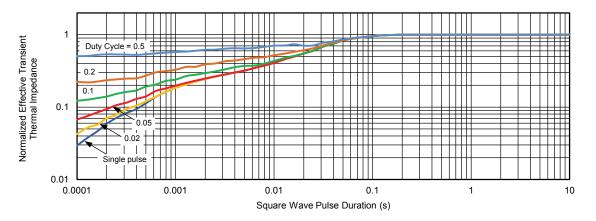
Normalized Thermal Transient Impedance, Junction-to-Ambient



SQD50034E

Vishay Siliconix

THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

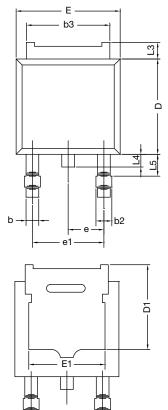
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

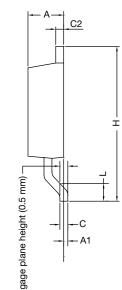
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?79706.





TO-252AA Case Outline



	MILLIN	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	4.10	-	0.161	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090 BSC		
e1	4.56	BSC	0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.01	1.52	0.040	0.060	
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019					

Note

• Dimension L3 is for reference only.

Ф **Т**



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)